

# **SPT7755**

# 8-BIT, 750 MSPS FLASH A/D CONVERTER

### **FEATURES**

- 1:2 Demuxed ECL Compatible Outputs
- Wide Input Bandwidth 900 MHz
- Low Input Capacitance 15 pF (MQUAD)
- Metastable Errors Reduced to 1 LSB
- · Monolithic for Low Cost
- Gray Code Output

### **APPLICATIONS**

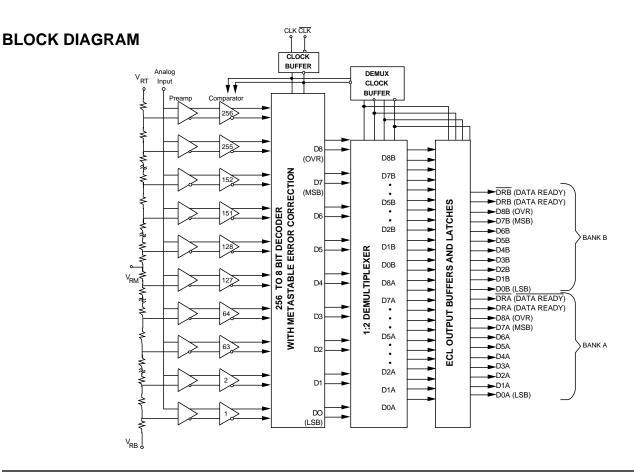
- Digital Oscilloscopes
- Transient Capture
- · Radar, EW, ECM
- Direct RF Down-Conversion

### **GENERAL DESCRIPTION**

The SPT7755 is a full parallel (flash) analog-to-digital converter capable of digitizing full scale (0 to -2 V) inputs into eight-bit digital words at an update rate of 750 MSPS. The ECL-compatible outputs are demultiplexed into two separate output banks, each with differential data ready outputs to ease the task of data capture. The SPT7755's wide input bandwidth and low capacitance eliminate the need for external track-and-hold amplifiers for most applications. A propri-

etary decoding scheme reduces metastable errors to the 1 LSB level. The SPT7755 operates from a single -5.2 V supply, with a nominal power dissipation of 5.5 W.

The SPT7755 is available in an 80L surface-mount MQUAD package over the industrial temperature range of -25 to +85 °C. Contact the factory for availability of die and /883 versions.



# Signal Processing Technologies, Inc.

4755 Forge Road, Colorado Springs, Colorado 80907, USA Phone: (719) 528-2300 FAX: (719) 528-2370

# ABSOLUTE MAXIMUM RATINGS (Beyond which damage may occur)1 25 °C

Supply Voltages  Negative Supply Voltage (V <sub>EE</sub> TO GND)7.0 to +0.5 V  Ground Voltage Differential0.5 to +0.5 V	Output Digital Output Current 0 to -28 mA
	Temperature
Input Voltage	Operating Temperature, ambient25 to +85 °C
Analog Input Voltage+0.5 V to VEE	case+125 °C
Reference Input Voltage+0.5 V to VEE	junction+150 °C
Digital Input Voltage+0.5 V to VEE	Lead Temperature, (soldering 10 seconds)+300 °C
Reference Current V <sub>RT</sub> to V <sub>RB</sub>	Storage Temperature65 to +150 °C

**Notes:** 1. Operation at any Absolute Maximum Rating is not implied. See Electrical Specifications for proper nominal applied conditions in typical applications.

### **ELECTRICAL SPECIFICATIONS**

 $T_{J} = T_{C} = T_{A} = +25 \, ^{\circ}\text{C} \; , \; V_{EE} = -5.2 \, \text{V}, \; V_{RB} = -2.00 \, \text{V}, \; V_{RM} = -1.0 \, \text{V}, \; V_{RT} = 0.00 \, \text{V}, \; f_{\text{clk}} = 750 \, \text{MHz}, \; \text{Duty Cycle} = 50\%, \; \text{unless otherwise specified}.$ 

	TEST	TEST	SPT7755A			SPT7755B			
PARAMETERS	CONDITIONS	LEVEL	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Resolution				8			8		Bits
DC Accuracy (+25 °C)									
Integral Nonlinearity	$f_{CLK} = 100 \text{ kHz}$	1	-1.0		+1.0	-1.5		+1.5	LSB
Differential Nonlinearity	f <sub>CLK</sub> = 100 kHz	1	-0.85		+0.95	-0.95		+1.5	LSB
No Missing Codes			(	Suarante	ed	0	Guarante	ed	
Analog Input									
Input Voltage Range		1	$V_{RB}$		$V_{RT}$	$V_{RB}$		$V_{RT}$	V
Input Bias Current	V <sub>IN</sub> =0 V	1		.75	2.0		.75	2.0	mA
Input Resistance		V		15			15		kΩ
Input Capacitance	Over Full Input Range	V		15			15		pF
Input Bandwidth									
Small Signal		V		900			900		MHz
Large Signal		V		500			500		MHz
Offset Error V <sub>RT</sub>		IV	-30		+30	-30		+30	mV
Offset Error V <sub>RB</sub>		IV	-30		+30	-30		+30	mV
Input Slew Rate		V		5			5		V/ns
Clock Synchronous									
Input Current		V		2			2		μΑ
Reference Input									
Ladder Resistance		1	60	80		60	80		Ω
Reference Bandwidth		V		30			30		MHz
Timing Characteristics									
Maximum Sample Rate		1	750			750			MHz
Aperture Jitter		V		2			2		ps
Acquisition Time		V		250			250		ps
CLK to Data Ready Delay		IV	0.9	1.4	1.9	0.9	1.4	1.9	ns
Clock to Data Delay		IV	1.25	1.75	2.25	1.25	1.75	2.25	ns
Dynamic Performance									
Signal-To-Noise Ratio									
(without Harmonics)									
$f_{IN} = 50 \text{ MHz}$		1	46			44			dB
f <sub>IN</sub> = 250 MHz		1	44			42			dB
Total Harmonic Distortion									
$f_{IN} = 50 \text{ MHz}$		1	-45			-43			dBc
f <sub>IN</sub> = 250 MHz		1	-37			-35			dBc



### **ELECTRICAL SPECIFICATIONS**

T<sub>J</sub> = T<sub>C</sub> = T<sub>A</sub> = +25 °C , V<sub>EE</sub>=-5.2 V, V<sub>RB</sub>=-2.00 V, V<sub>RM</sub>=-1.0 V, V<sub>RT</sub>=0.00 V, f<sub>Clk</sub>=750 MHz, Duty Cycle=50%, unless otherwise specified.

	TEST	TEST		SPT7755	A		SPT7755	5B	
PARAMETERS	CONDITIONS	LEVEL	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Dynamic Performance									
Signal-to-Noise and Distortion									
f <sub>IN</sub> = 50 MHz		I	43			41			dB
f <sub>IN</sub> = 250 MHz		I	36			34			dB
Spurious Free Dynamic Range									
$f_{IN} = 50 \text{ MHz}$		I	48			44			dB
$f_{IN} = 250 \text{ MHz}$		I	40			36			dB
Digital Inputs									
Input High Voltage									
(CLK, NCLK)		I	-1.1	-0.7		-1.1	-0.7		V
Input Low Voltage									
(CLK, NCLK)		I		-1.8	-1.5		-1.8	-1.5	V
Clock Pulse Width High (t <sub>PWH</sub> )		I	0.67	0.5		0.67	0.5		ns
Clock Pulse Width Low (t <sub>PWL</sub> )		I	0.67	0.5		0.67	0.5		ns
Digital Outputs									
Logic "1" Voltage		I	-1.1	-0.9		-1.1	-0.9		V
Logic "0" Voltage		I		-1.8	-1.5		-1.8	-1.5	V
Rise Time	20 to 80%	V		450			450		ps
Fall Time	20 to 80%	V		450			450		ps
Power Supply Requirements									
Voltage V <sub>EE</sub>		IV	-4.95	-5.2	-5.45	-4.95	-5.2	-5.45	V
Current I <sub>EE</sub>				1.05	1.2		1.05	1.2	Α
Power Dissipation		I		5.5	6.25		5.5	6.25	W

Typical Thermal Impedance:  $\theta_{JC} = +4 \, ^{\circ}C/W$ .

### **TEST LEVEL CODES**

All electrical characteristics are subject to the following conditions:

All parameters having min/max specifications are guaranteed. The Test Level column indicates the specific device testing actually performed during production and Quality Assurance inspection. Any blank section in the data column indicates that the specification is not tested at the specified condition.

Unless otherwise noted, all tests are pulsed tests; therefore,  $T_J = T_C = T_A$ .

### TEST LEVEL TEST PROCEDURE

1	100% production tested at the specified temperature.
II	100% production tested at $T_A$ =25 °C, and sample tested at the specified temperatures.
Ш	QA sample tested only at the specified temperatures.
IV	Parameter is guaranteed (but not tested) by design and characterization data.
V	Parameter is a typical value for information purposes only.
VI	100% production tested at $T_A$ = 25 °C. Parameter is guaranteed over specified temperature range.



SPT7755 3/5/97

### **GENERAL DESCRIPTION**

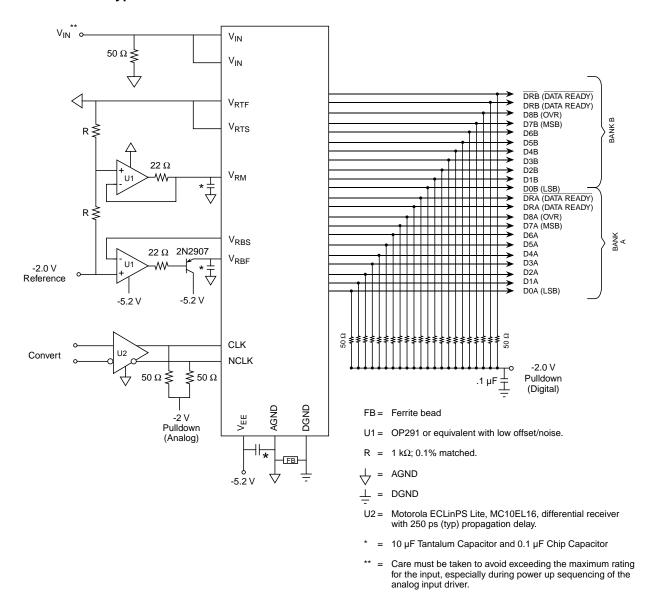
The SPT7755 is one of the fastest monolithic 8-bit parallel flash A/D converters available today. The nominal conversion rate is 750 MSPS and the analog bandwidth is in excess of 900 MHz. A major advance over previous flash converters is the inclusion of 256 input preamplifiers between the reference ladder and input comparators (see block diagram). This not only reduces clock transient kickback to the input and reference ladder due to a low AC beta but also reduces the effect of the dynamic state of the input signal on the latching characteristics of the input comparators. The preamplifiers act as buffers and stabilize the input capacitance so that it remains constant over different input voltage

and frequency ranges and therefore makes the part easier to drive than previous flash converters. The preamplifiers also add a gain of two to the input signal so that each comparator has a wider overdrive or threshold range to "trip" into or out of the active state. This gain reduces metastable states that can cause errors at the output.

The SPT7755 has true differential analog and digital data paths from the preamplifiers to the output buffers (Current Mode Logic) for reducing potential missing codes while rejecting common mode noise.

Signature errors are also reduced by careful layout of the analog circuitry. The output drive capability of the device can provide full ECL swings into 50  $\Omega$  loads.

Figure 1 - SPT7755 Typical Interface Circuit



### TYPICAL INTERFACE CIRCUIT

The circuit in figure 1 is intended to show the most elaborate method of achieving the least error by correcting for integral linearity, input induced distortion and power supply/ground noise. This is achieved by the use of external reference ladder tap connections, input buffer and supply decoupling. Please contact the factory for the SPT7755 evaluation board applications note that contains more details on interfacing the SPT7755. The function of each pin and external connections to other components is as follows:

### VEE, AGND, DGND

VEE is the supply pin with AGND as ground for the device. The power supply pins should be bypassed as close to the device as possible with at least a .01  $\mu\text{F}$  ceramic capacitor. A 1  $\mu\text{F}$  tantalum can also be used for low frequency suppression. DGND is the ground for the ECL outputs and is to be referenced to the output pulldown voltage and appropriately bypassed as shown in figure 5.

### **VIN (ANALOG INPUT)**

There are two analog input pins that are tied to the same point internally. Either one may be used as an analog input sense and the other for input force. This is convenient for testing the source signal to see if there is sufficient drive capability. The pins can also be tied together and driven by the same source. The SPT7755 is superior to similar devices due to a preamplifier stage before the comparators. This makes the device easier to drive because it has constant capacitance and induces less slew rate distortion.

## CLK, CLK (CLOCK INPUTS)

The clock inputs are designed to be driven differentially with ECL levels. The duty cycle of the clock should be kept at 50% to avoid causing larger second harmonics. If this is not important to the intended application, then duty cycles other than 50% may be used.

### D0 TO D8, DR, NDR (A AND B)

The digital outputs can drive 50  $\Omega$  to ECL levels when pulled down to -2 V. When pulled down to -5.2 V, the outputs can drive 130  $\Omega$  to 1 k $\Omega$  loads. All digital outputs are grey code with the coding as shown in table 1.

# V<sub>RBF</sub>, V<sub>RBS</sub>, V<sub>RTF</sub>, V<sub>RTS</sub>, V<sub>RM</sub> (REFERENCE INPUTS)

There are two reference inputs and one external reference voltage tap. These are -2 V ( $V_{RB}$  force and sense), mid-tap

 $(V_{RM})$  and AGND ( $V_{RT}$  force and sense). The reference pins and tap can be driven by op amps as shown in figure 1 or  $V_{RM}$  may be bypassed for limited temperature operation. These voltage inputs can be bypassed to AGND for further noise suppression if so desired.

**Table I - Output Coding** 

V <sub>IN</sub>	D8	D7 ••• D0
> -0.5 LSB	1	10000000
-0.5 LSB	1 0	10000000
-1.5 LSB	0	10000000
•	•	•
-1.0 V	0	11000000
•	•	•
-2.0 V+ 1/2 LSB	0	00000001
< (-2.0 V +1/2 LSB)	0	00000000

Indicates the transition between the two codes

### THERMAL MANAGEMENT

The typical thermal impedance is as follows:

 $\Theta$ CA = +17 °C/W in still air with no heat sink

We highly recommend that a heat sink be used for this device with adequate air flow to ensure rated performance of the device. We have found that a Thermalloy 17846 heat sink with a minimum air flow of 1 meter/second (200 linear feet per minute) provides adequate thermal performance under laboratory tests. Application specific conditions should be taken into account to ensure that the device is properly heat sinked.



**SPT7755** 

### **OPERATION**

The SPT7755 has 256 preamp/comparator pairs which are each supplied with the voltage from  $V_{RT}$  to  $V_{RB}$  divided equally by the resistive ladder as shown in the block diagram. This voltage is applied to the positive input of each preamplifier/comparator pair. An analog input voltage applied at  $V_{IN}$  is connected to the negative inputs of each preamplifier/comparator pair. The comparators are then clocked through each one's individual clock buffer. When the CLK pin is in the low state, the master or input stage of the comparators compare the analog input voltage to the respective reference voltage. When the CLK pin changes from low to high the comparators

are latched to the state prior to the clock transition and output logic codes in sequence from the top comparators, closest to  $V_{RT}\,(0\,V),$  down to the point where the magnitude of the input signal changes sign (thermometer code). The output of each comparator is then registered into four 64-to-6 bit decoders when the CLK is changed from high to low. At the output of the decoders is a set of four 7-bit latches which are enabled ("track") when the clock changes from high to low. From here, the output of the latches are coded into 6 LSBs from 4 columns and 4 columns are coded into 2 MSBs. Finally, 8 ECL output latches and buffers are used to drive the external loads. The conversion takes one clock cycle from the input to the data outputs.

Figure 2 - Timing Diagram

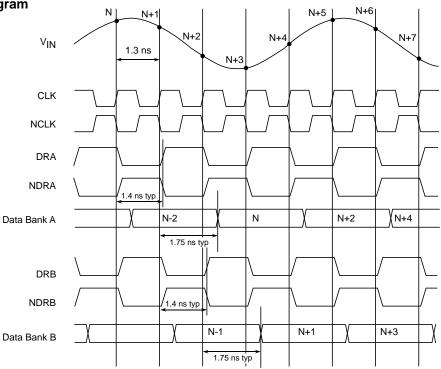
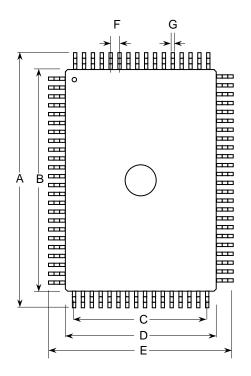


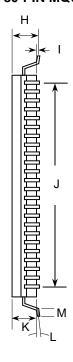
Figure 3 - Subcircuit Schematics

# INPUT CIRCUIT OUTPUT CIRCUIT CLOCK INPUT AGND OUTPUT CIRCUIT CLICK INPUT CLICK INPUT CLICK INPUT



# PACKAGE OUTLINE 80-PIN MQUAD





	INCHE	S	MILLIMETERS		
SYMBOL	MIN	MAX	MIN	MAX	
Α	0.937	0.945	23.80	24.00	
В	0.777	0.785	19.72	19.93	
С	0.472 TYP		12.0 TYP		
D	0.541	0.549	13.73	13.94	
Е	0.701	0.709	17.80	18.00	
F	0.032 TYP		0.80 TYP		
G	0.014 TYP		0.36 TYP		
Н	0.114	0.122	2.90	3.10	
- 1	.006 TYP		0.15 TYP		
J	0.724 TYP		18.4 TYP		
K	0.099	0.109	2.51	2.77	
L	7°		7°		
М	0.026	0.036	0.66	0.91	